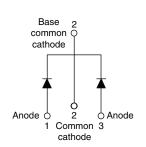


Vishay Semiconductors

Schottky Rectifier, 2 x 20 A

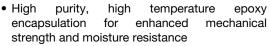




PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 20 A			
V_{R}	30 V			
V _F at I _F	0.38 V			
I _{RM} max.	183 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Common cathode			
E _{AS}	13 mJ			

FEATURES

- 150 °C T_J operation
- · Very low forward voltage drop





HALOGEN

FREE

- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICSL						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	Α			
V _{RRM}		30	V			
I _{FSM}	t _p = 5 μs sine	1100	Α			
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.38	V			
T _J	Range	- 55 to 150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-42CTQ030PbF	VS-142TQ030-N3	UNITS		
Maximum DC reverse voltage	V _R	30	30	V		
Maximum working peak reverse voltage	V_{RWM}	30	30	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average per leg		50 % duty cycle at T _C = 121 °C, rectangular waveform		20		
See fig. 5 per device	I _{F(AV)}			40	Α	
Maximum peak one cycle non-repetitive surge current per leg		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1100		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	360		
Non-repetitive avalanche energy per leg E,		$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 2.90 \text{mH}$		13	mJ	
Repetitive avalanche current per leg I _{AR}		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А	



VS-42CTQ030PbF, VS-42CTQ030-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		20 A	T _{.1} = 25 °C	0.48	V	
Maximum forward voltage drop per leg	V (1)	40 A	1j=25 C	0.57		
See fig. 1	V _{FM} ⁽¹⁾	20 A	T 105 °C	0.38		
		40 A	T _J = 125 °C	0.51		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V DetectV	3	mA	
See fig. 2		T _J = 125 °C	V _R = Rated V _R	183		
Threshold voltage	V _{F(TO)}	T T		0.22	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		6.76	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	2840	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range	ge	T _J , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistance junction to case per leg	,		DC operation	2.0		
Maximum thermal resistance junction to case per package	•	R _{thJC}	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Manustina taunus	minimum			6 (5)	kgf ⋅cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking device Case style TO-220AB		Case style TO-220AB	42CT	Q030		



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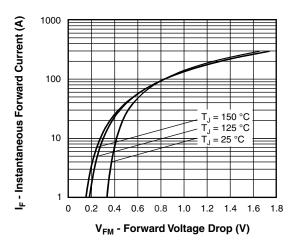


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

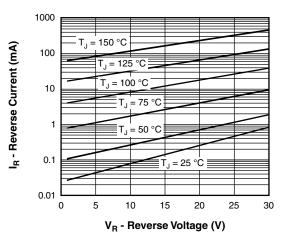


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

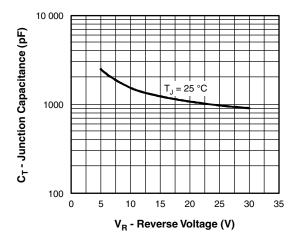


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

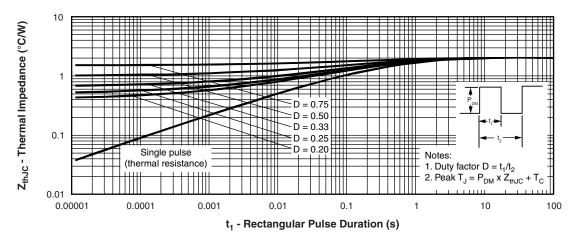


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



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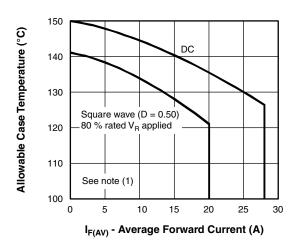


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

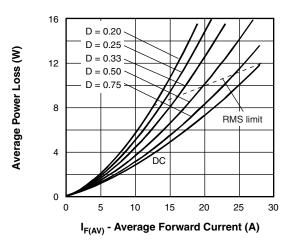


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

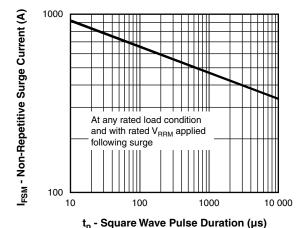


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

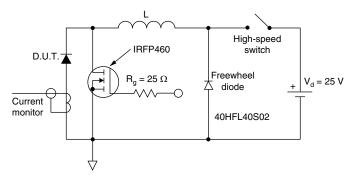


Fig. 8 - Unclamped Inductive Test Circuit

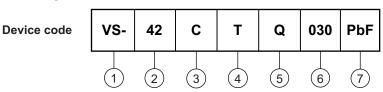
Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at (I_{F(AV)}/D) (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 10 \text{ V}$

VS-42CTQ030PbF, VS-42CTQ030-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

Current rating (40 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

Voltage rating (030 = 30 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-42CTQ030PbF	50	1000	Antistatic plastic tube			
VS-42CTQ030-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95222</u>				
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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